DATA SHEET

SA616
Low-voltage high performance mixer FM IF system

Product specification
Replaces data of 1993 Dec 15
IC17 Data Handbook

1997 Nov 07

Philips Semiconductors

PHILIPS

Low-voltage high performance mixer FM IF system — SA616

DESCRIPTION

The SA616 is a low-voltage high performance monolithic FM IF system incorporating a mixer/oscillator, two limiting intermediate frequency amplifiers, quadrature detector, logarithmic received signal strength indicator (RSSI), voltage regulator and audio and RSSI op amps. The SA616 is available in 20-lead SSOP (shrink small outline package).

The SA616 was designed for portable communication applications and will function down to 2.7V. The RF section is similar to the famous SA615. The audio and RSSI outputs have amplifiers with access to the feedback path. This enables the designer to adjust the output levels or add filtering.

FEATURES

- Low power consumption: 3.5mA typical at 3V
- Mixer input to >150MHz
- Mixer conversion power gain of 17dB at 45MHz
- XTAL oscillator effective to 150MHz (L.C. oscillator or external oscillator can be used at higher frequencies)
- 102dB of IF Amp/Limiter gain
- 2MHz IF amp/limiter small signal bandwidth
- Temperature compensated logarithmic Received Signal Strength Indicator (RSSI) with a 80dB dynamic range
- Low external component count; suitable for crystal/ceramic/LC filters
- Excellent sensitivity: 0.31µV into 50Ω matching network for 12dB SINAD (Signal to Noise and Distortion ratio) for 1kHz tone with RF at 45MHz and IF at 455kHz
- SA616 meets cellular radio specifications
- Audio output internal op amp
- RSSI output internal op amp
- Internal op amps with rail-to-rail outputs
- ESD protection: Human Body Model 2kV
Robot Model 200V

PIN CONFIGURATION

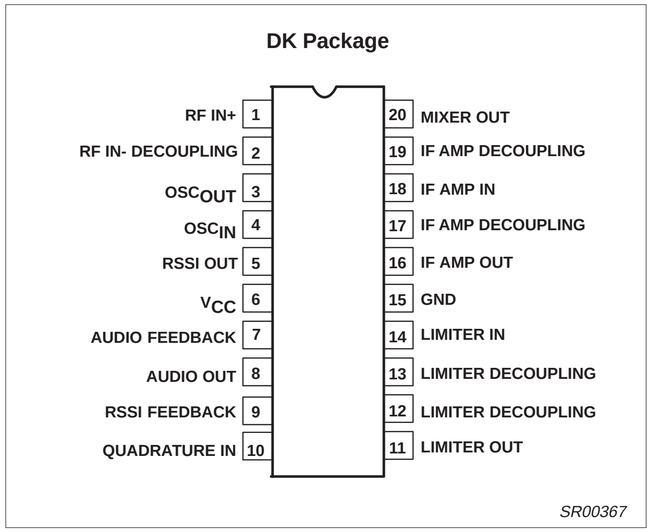


Figure 1. Pin Configuration

APPLICATIONS

- Portable cellular radio FM IF
- Cordless phones
- Wireless systems
- RF level meter
- Spectrum analyzer
- Instrumentation
- FSK and ASK data receivers
- Log amps
- Portable high performance communication receiver
- Single conversion VHF receivers

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
20-Pin Plastic Shrink Small Outline Package (SSOP) (Surface-mount)	-40 to +85°C	SA616DK	SOT266-1

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V_{CC}	Single supply voltage	7	V
T_{STG}	Storage temperature range	-65 to +150	°C
T_A	Operating ambient temperature range	-40 to +85	°C
θ_{JA}	Thermal impedance DK package	117	°C/W

BLOCK DIAGRAM

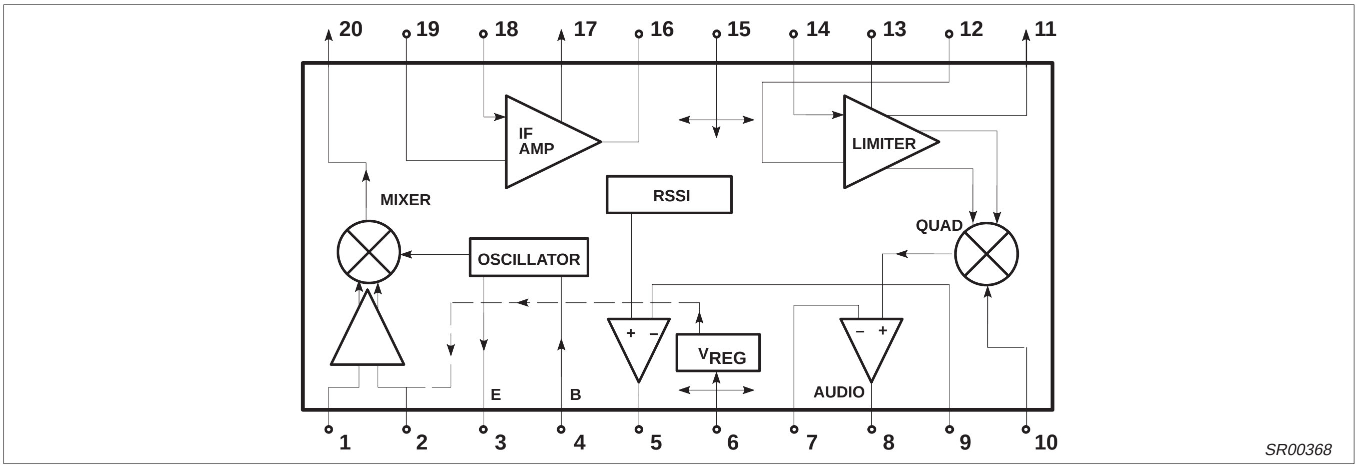


Figure 2. Block Diagram

DC ELECTRICAL CHARACTERISTICS

V_{CC} = +3V, T_A = 25°C; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
V_{CC}	Power supply voltage range		2.7		7.0	V
I_{CC}	DC current drain			3.5	5.0	mA

AC ELECTRICAL CHARACTERISTICS

T_A = 25°C; V_{CC} = +3V, unless otherwise stated. RF frequency = 45MHz + 14.5dBV RF input step-up; IF frequency = 455kHz; R17 = 2.4kΩ and R18 = 3.3kΩ; RF level = -45dBm; FM modulation = 1kHz with ±8kHz peak deviation. Audio output with de-emphasis filter and C-message weighted filter. Test circuit Figure 3. The parameters listed below are tested using automatic test equipment to assure consistent electrical characterristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout will improve many of the listed parameters.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Mixer/Osc section (ext LO = 220mV$_{RMS}$)						
f_{IN}	Input signal frequency			150		MHz
f_{OSC}	Crystal oscillator frequency			150		MHz
	Noise figure at 45MHz			6.8		dB
	Third-order input intercept point (50Ω source)	f1 = 45.0; f2 = 45.06MHz Input RF level = -52dBm		-9		dBm
	Conversion power gain	Matched 14.5dBV step-up	11	17		dB
		50Ω source		+2.5		dB
	RF input resistance	Single-ended input		8		kΩ
	RF input capacitance			3.0	4.0	pF
	Mixer output resistance	(Pin 20)	1.25	1.5		kΩ
IF section						
	IF amp gain	50Ω source		44		dB
	Limiter gain	50Ω source		58		dB
	Input limiting -3dB, R_{17a} = 2.4k, R_{17b} = 3.3k	Test at Pin 18		-105		dBm
	AM rejection	80% AM 1kHz		40		dB
	Audio level	Gain of two (2kΩ AC load)	60	120		mV
	SINAD sensitivity	IF level -110dBm		17		dB
THD	Total harmonic distortion		-30	-45		dB

AC ELECTRICAL CHARACTERISTICS (Continued)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
S/N	Signal-to-noise ratio	No modulation for noise		62		dB
	RF RSSI output, $R_9 = 2k\Omega$	RF level = -118dBm		0.3	.80	V
		RF level = -68dBm	.70	1.1	2	V
		RF level = -23dBm	1.0	1.8	2.50	V
	RSSI range			80		dB
	RSSI accuracy			$\pm$2		dB
	IF input impedance	Pin 18	1.3	1.5		kΩ
	IF output impedance	Pin 16		0.3		kΩ
	Limiter input impedance	Pin 14	1.3	1.5		kΩ
	Limiter output impedance	Pin 11		0.3		kΩ
	Limiter output voltage	Pin 11		130		mV_{RMS}
RF/IF section (int LO)						
	Audio level	$3V = V_{CC}$, RF level = -27dBm		120		mV_{RMS}
	System RSSI output	$3V = V_{CC}$, RF level = -27dBm		2.2		V
	System SINAD sensitivity	RF level = -117dBm		12		dB

CIRCUIT DESCRIPTION

The SA616 is an IF signal processing system suitable for second IF systems with input frequency as high as 150MHz. The bandwidth of the IF amplifier and limiter is at least 2MHz with 90dB of gain. The gain/bandwidth distribution is optimized for 455kHz, 1.5kΩ source applications. The overall system is well-suited to battery operation as well as high performance and high quality products of all types.

The input stage is a Gilbert cell mixer with oscillator. Typical mixer characteristics include a noise figure of 6.2dB, conversion gain of 17dB, and input third-order intercept of -9dBm. The oscillator will operate in excess of 200MHz in L/C tank configurations. Hartley or Colpitts circuits can be used up to 100MHz for xtal configurations. Butler oscillators are recommended for xtal configurations up to 150MHz.

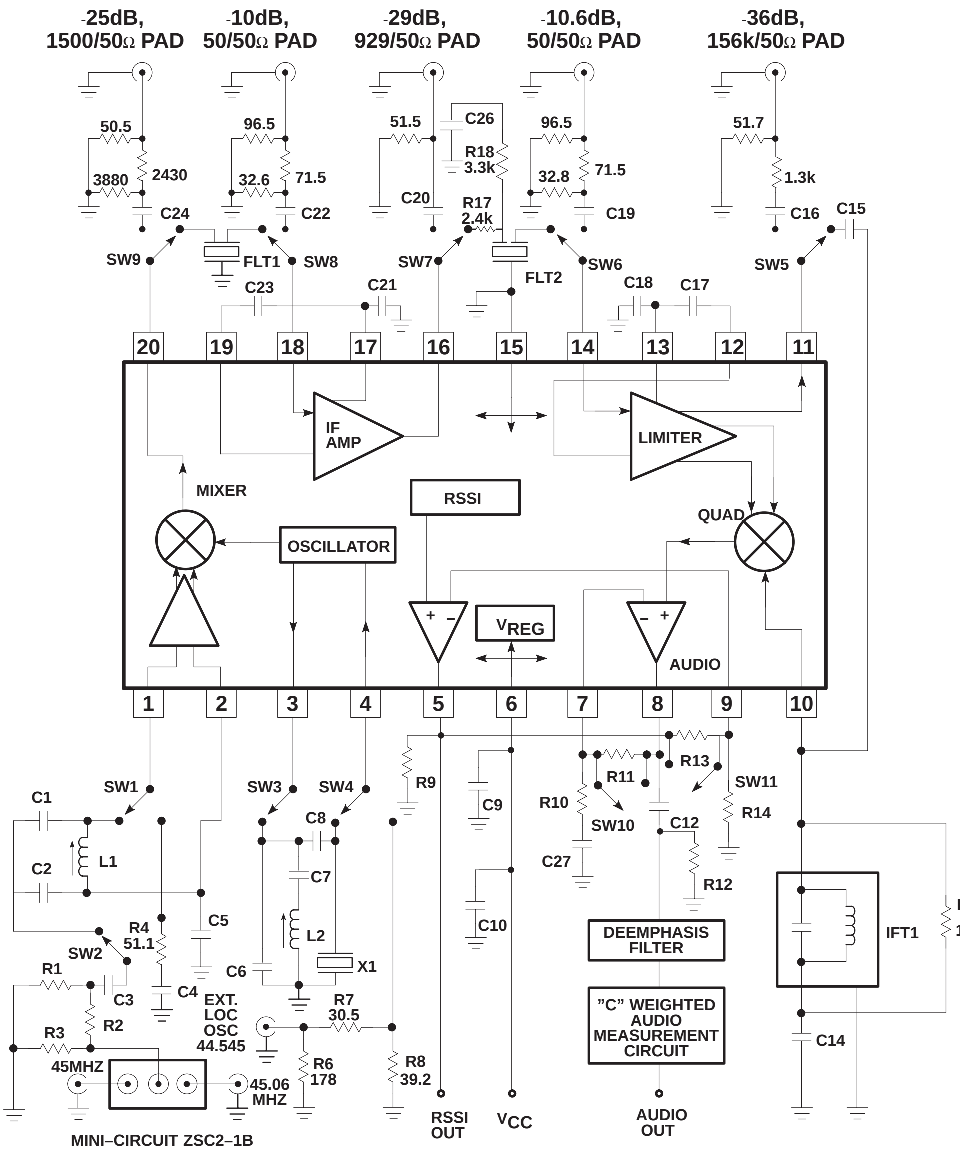
The output impedance of the mixer is a 1.5kΩ resistor permitting direct connection to a 455kHz ceramic filter. The input resistance of the limiting IF amplifiers is also 1.5kΩ. With most 455kHz ceramic filters and many crystal filters, no impedance matching network is necessary. The IF amplifier has 43dB of gain and 5.5MHz bandwidth. The IF limiter has 60dB of gain and 4.5MHz bandwidth. To achieve optimum linearity of the log signal strength indicator, there must be a 12dB(v) insertion loss between the first and second IF stages. If the IF filter or interstage network does not cause 12dB(v) insertion loss, a fixed or variable resistor or an L pad for simultaneous loss and impedance matching can be added between the first IF output (Pin 16) and the interstage network. The overall gain will then be 90dB with 2MHz bandwidth.

The signal from the second limiting amplifier goes to a Gilbert cell quadrature detector. One port of the Gilbert cell is internally driven by the IF. The other output of the IF is AC-coupled to a tuned quadrature network. This signal, which now has a 90° phase relationship to the internal signal, drives the other port of the multiplier cell.

The demodulated output of the quadrature drives an internal op amp. This op amp can be configured as a unity gain buffer, or for simultaneous gain, filtering, and 2nd-order temperature compensation if needed. It can drive an AC load as low as 5kΩ with a rail-to-rail output.

A log signal strength completes the circuitry. The output range is greater than 90dB and is temperature compensated. This log signal strength indicator exceeds the criteria for AMPs or TACs cellular telephone. This signal drives an internal op amp. The op amp is capable of rail-to-rail output. It can be used for gain, filtering, or 2nd-order temperature compensation of the RSSI, if needed.

NOTE: $dB(v) = 20\log V_{OUT}/V_{IN}$



Automatic Test Circuit Component List

C1	100pF NPO Ceramic	C27	100nF ±10% Monolithic Ceramic
C2	390pF NPO Ceramic	Flt 1	Ceramic Filter Murata SFG455A3 or equiv
C5	100nF ±10% Monolithic Ceramic	Flt 2	Ceramic Filter Murata SFG455A3 or equiv
C6	22pF NPO Ceramic	IFT 1	455kHz (Ce = 180pF) Toko RMC–2A6597H
C7	1nF Ceramic	L1	147–160nH Coilcraft UNI–10/142–04J08S
C8	10.0pF NPO Ceramic	L2	0.8μH nominal
C9	100nF ±10% Monolithic Ceramic		Toko 292CNS–T1038Z
C10	15μF Tantalum (minimum)	X1	44.545MHz Crystal ICM4712701
C12	2.2μF	R9	2kΩ ±1% 1/4W Metal Film
C14	100nF ±10% Monolithic Ceramic	R10	8.2kΩ ±1%
C15	10pF NPO Ceramic	R11	10kΩ ±1%
C17	100nF ±10% Monolithic Ceramic	R12	2kΩ ±1%
C18	100nF ±10% Monolithic Ceramic	R13	20kΩ ±1%
C21	100nF ±10% Monolithic Ceramic	R14	10kΩ ±1%
C23	100nF ±10% Monolithic Ceramic	R17	2.4kΩ ±5% 1/4W Carbon Composition
C25	100nF ±10% Monolithic Ceramic	R18	3.3kΩ
C26	100nF ±10% Monolithic Ceramic	R19	16kΩ

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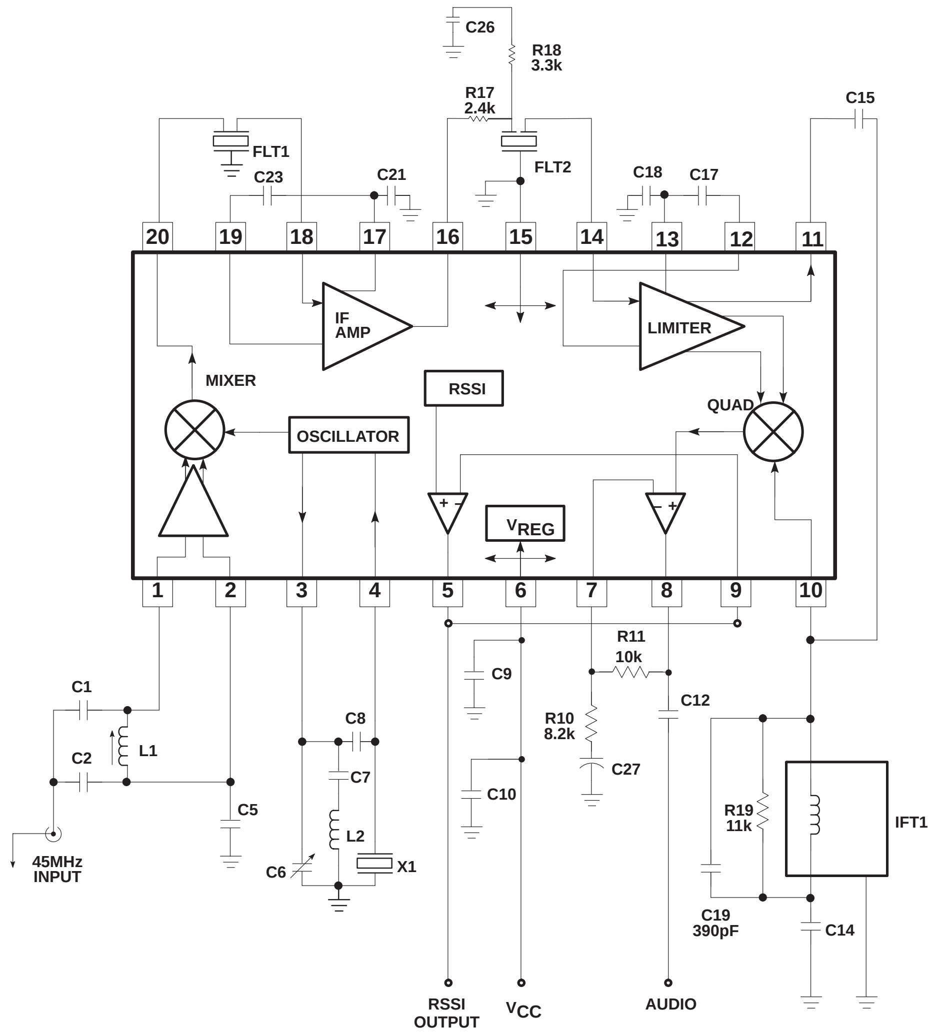
Figure 3. SA616 45MHz Test Circuit (Relays as shown)



SA616 DK demoboard
Application Component List

C1	51pF NPO Ceramic
C2	220pF NPO Ceramic
C5	100nF +10% Monolithic Ceramic
C6	30pF trim cap
C7	1nF Ceramic
C8	10.0pF NPO Ceramic
C9	100nF +10% Monolithic Ceramic
C10	15µF Tantalum (minimum)
C12	2.2µF +10% Tantalum
C14	100nF +10% Monolithic Ceramic
C15	10pF NPO Ceramic
C17	100nF +10% Monolithic Ceramic
C18	100nF +10% Monolithic Ceramic
C19	390pF +10% Monolithic Ceramic
C21	100nF +10% Monolithic Ceramic
C23	100nF +10% Monolithic Ceramic
C26	100nF +10% Monolithic Ceramic
C27	2.2µF Tantalum
Flt 1	Ceramic Filter Murata SFG455A3 or equiv
Flt 2	Ceramic Filter Murata SFG455A3 or equiv
IFT 1	330µH TOKO 303LN-1130
L1	.33µH TOKO SCB-1320Z
L2	1.2µH
X1	44.545MHz Crystal ICM4712701
R5	Not Used in Application Board (see Note 8, pg 8)
R10	8.2k +5% 1/4W Carbon Composition
R11	10k +5% 1/4W Carbon Composition
R17	2.4k +5% 1/4W Carbon Composition
R18	3.3k +5% 1/4W Carbon Composition
R19	11k +5% 1/4W Carbon Composition

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Figure 4. SA616 45MHz Application Circuit

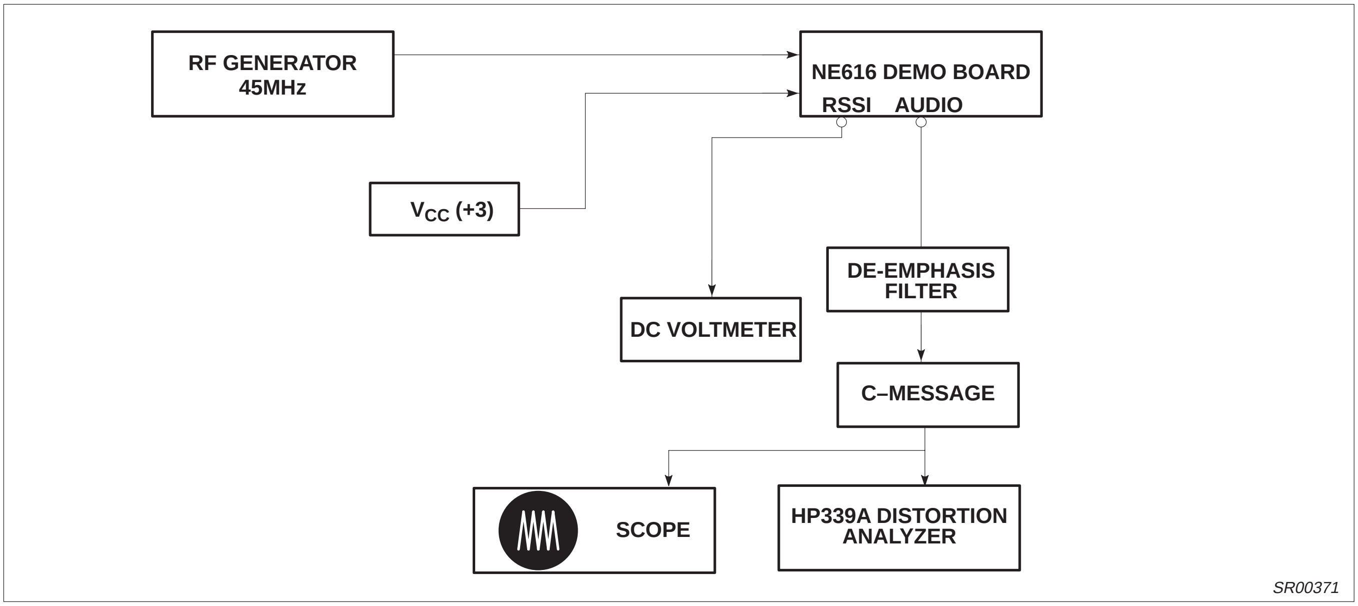


Figure 5. SA616 Application Circuit Test Set Up

NOTES:
1. C-message: The C-message and de-emphasis filter combination has a peak gain of 10 for accurate measurements. Without the gain, the measurements may be affected by the noise of the scope and HP339 analyzer. The de-emphasis filter has a fixed -6dB/Octave slope between 300Hz and 3kHz.
2. Ceramic filters: The ceramic filters can be 30kHz SFG455A3s made by Murata which have 30kHz IF bandwidth (they come in blue), or 16kHz CFU455Ds, also made by Murata (they come in black). All of our specifications and testing are done with the more wideband filter.
3. RF generator: Set your RF generator at 45.000MHz, use a 1kHz modulation frequency and a 6kHz deviation if you use 16kHz filters, or 8kHz if you use 30kHz filters.
4. Sensitivity: The measured typical sensitivity for 12dB SINAD should be 0.35µV or -116dBm at the RF input.
5. Layout: The layout is very critical in the performance of the receiver. We highly recommend our demo board layout.
6. RSSI: The smallest RSSI voltage (i.e., when no RF input is present and the input is terminated) is a measure of the quality of the layout and design. If the lowest RSSI voltage is 500mV or higher, it means the receiver is in regenerative mode. In that case, the receiver sensitivity will be worse than expected.
7. Supply bypass and shielding: All of the inductors, the quad tank, and their shield must be grounded. A 10-15µF or higher value tantalum capacitor on the supply line is essential. A low frequency ESR screening test on this capacitor will ensure consistent good sensitivity in production. A 0.1µF bypass capacitor on the supply pin, and grounded near the 44.545MHz oscillator improves sensitivity by 2-3dB.
8. R5 can be used to bias the oscillator transistor at a higher current for operation above 45MHz. Recommended value is 22kΩ, but should not be below 10kΩ.

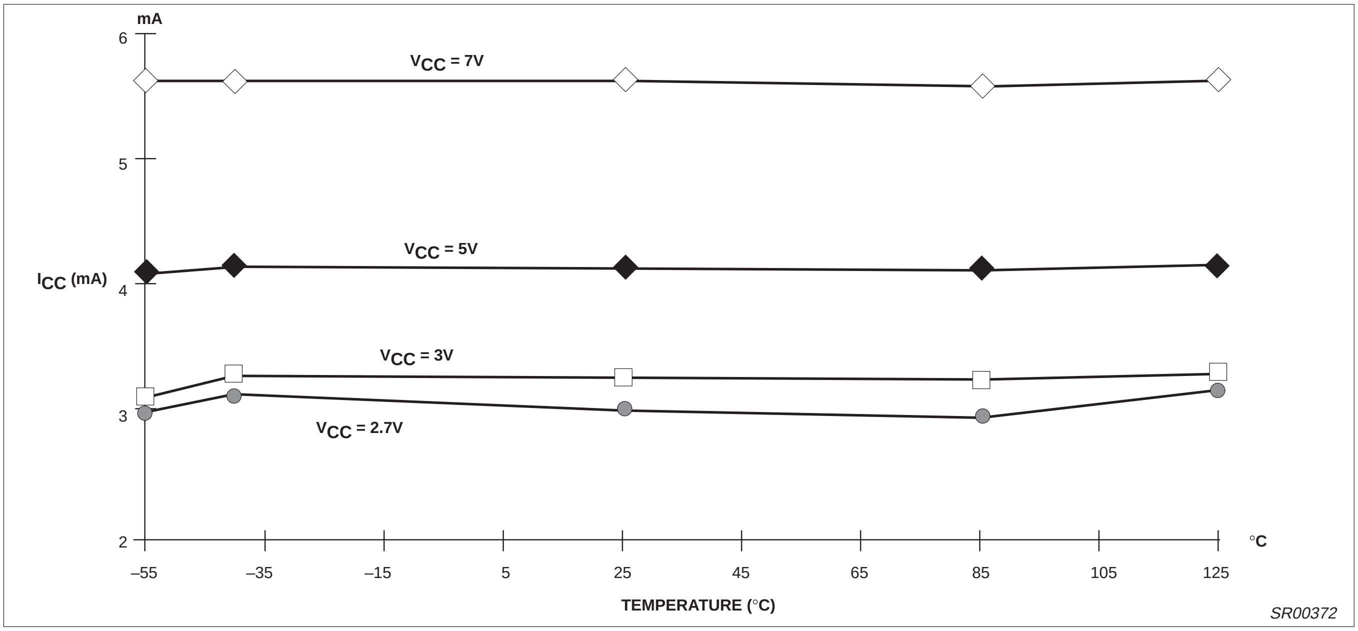


Figure 6. I_{CC} vs Temperature

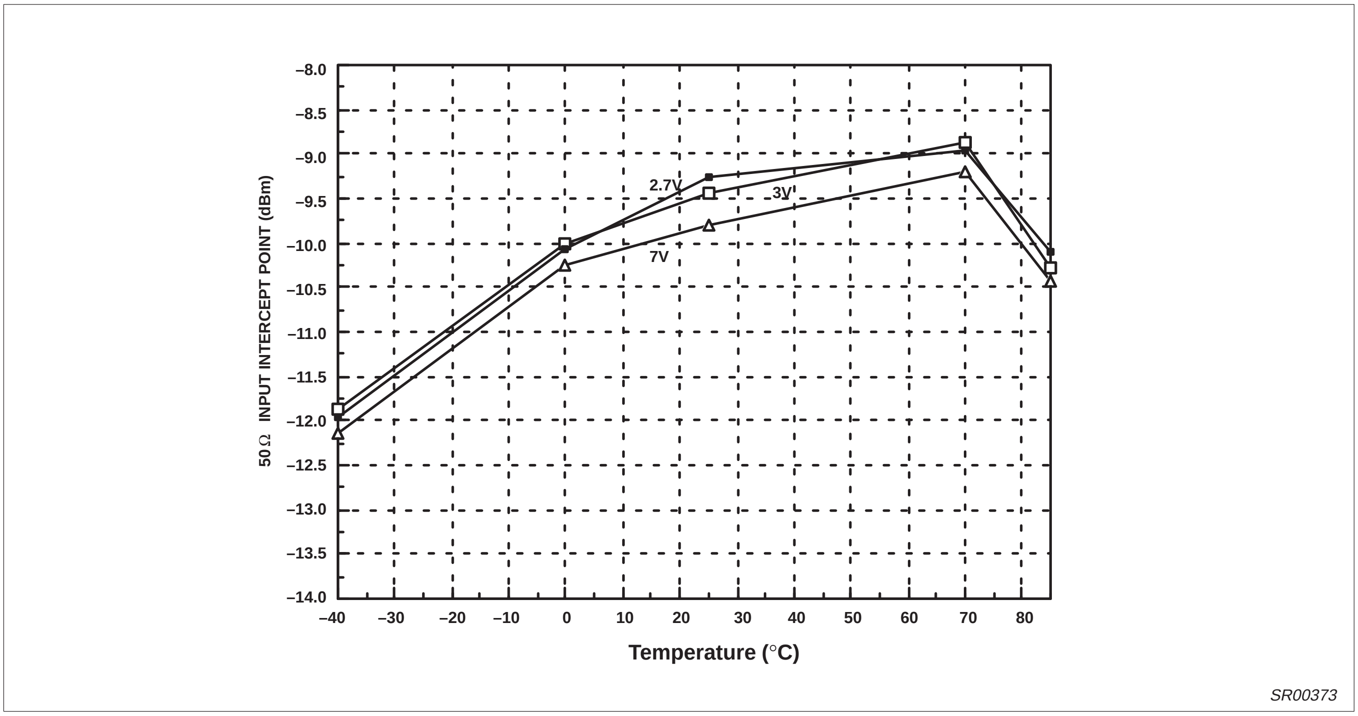


Figure 7. Third Order Intercept Point vs Supply Voltage

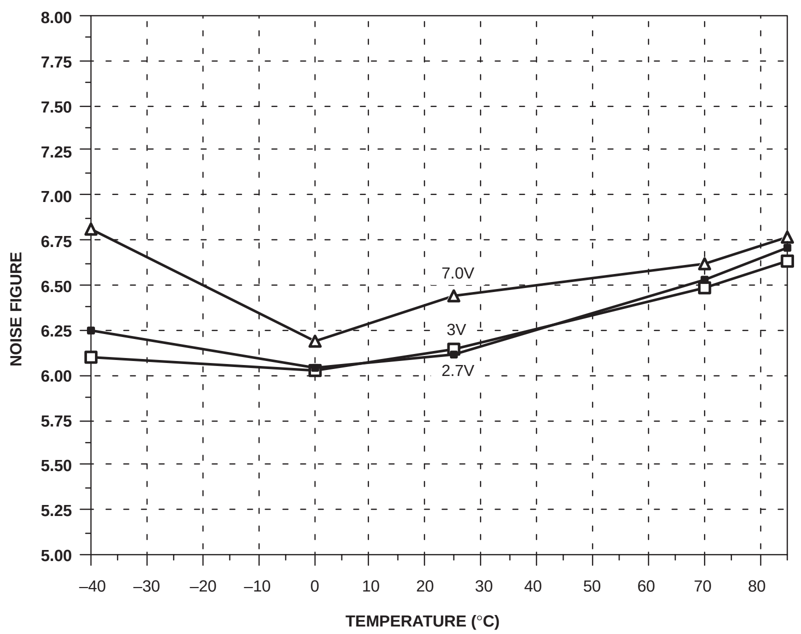


Figure 8. Mixer Noise Figure vs Supply Voltage

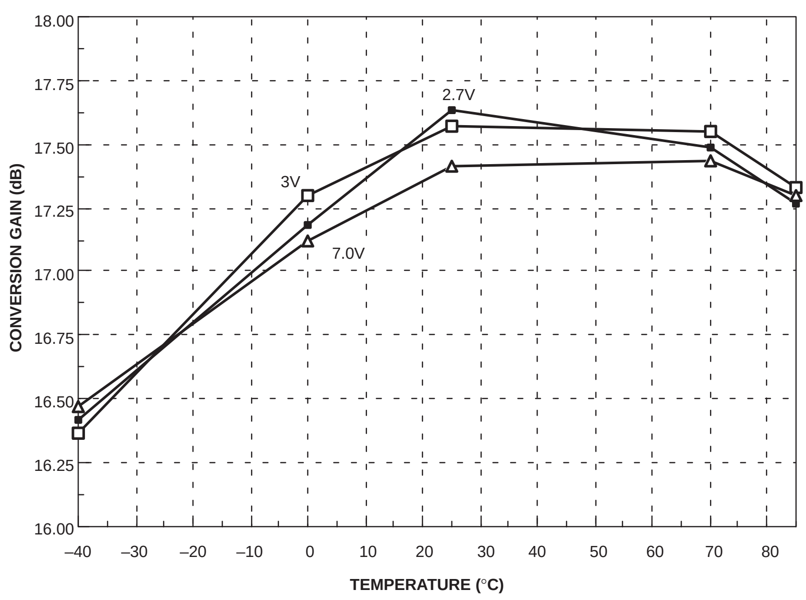


Figure 9. Conversion Gain vs Supply Voltage

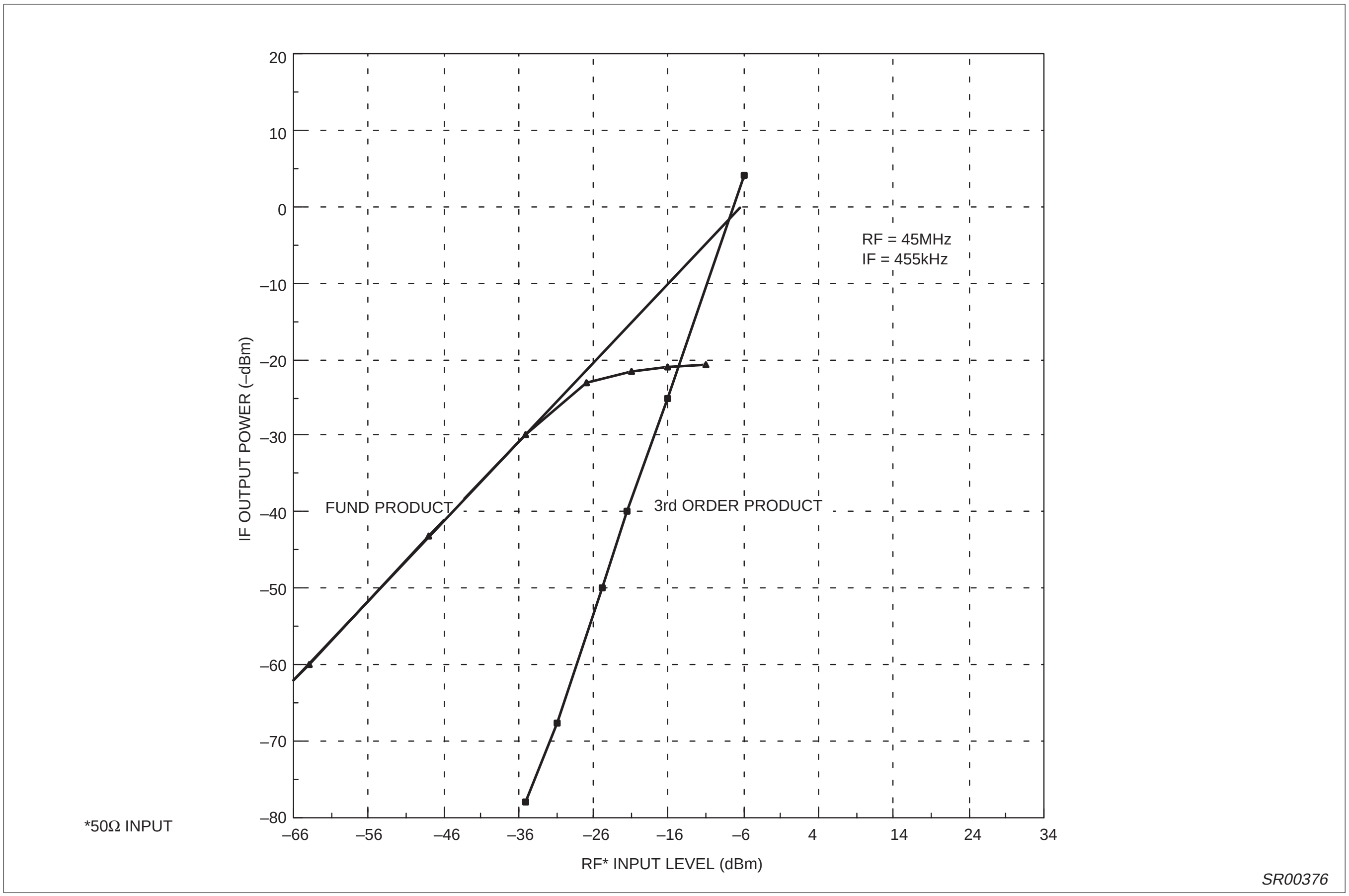


Figure 10. Mixer Third Order Intercept and Compression

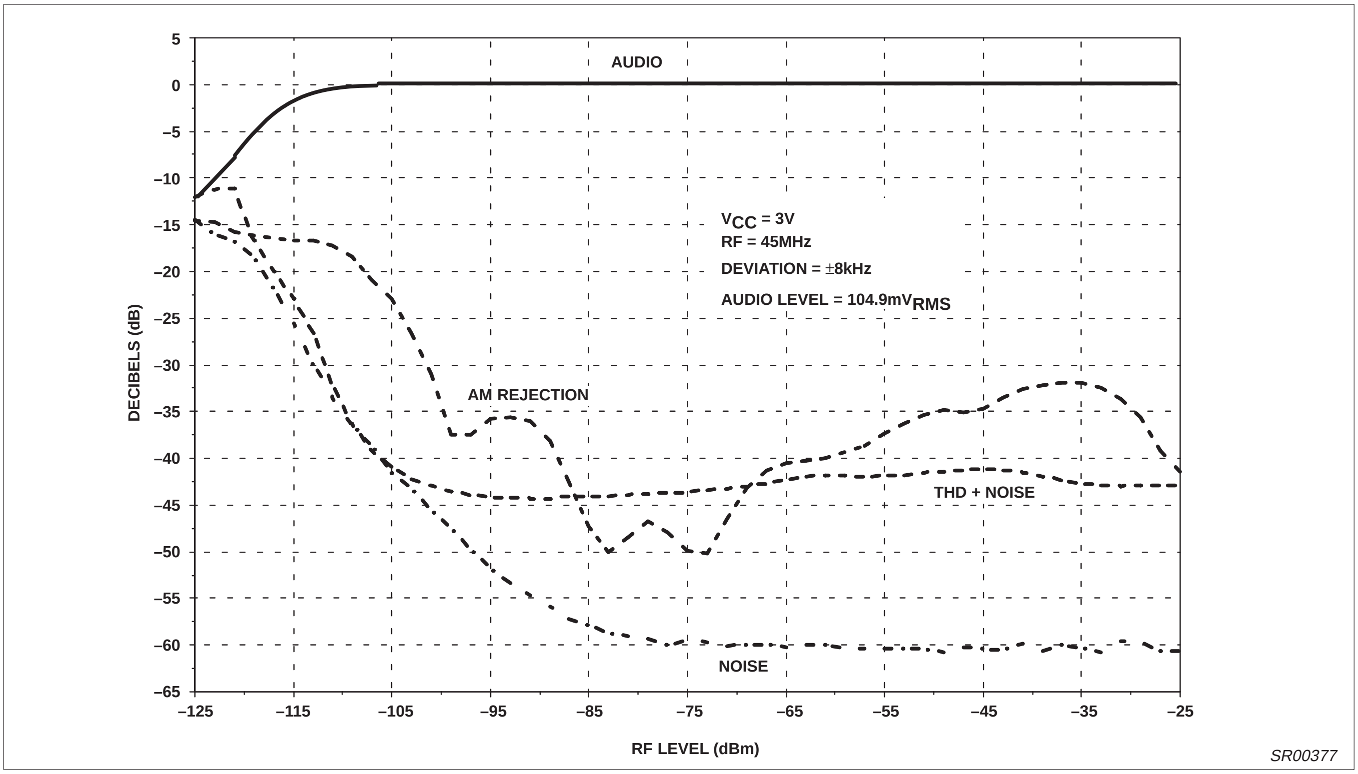


Figure 11. Sensitivity vs RF Level (-40°C)

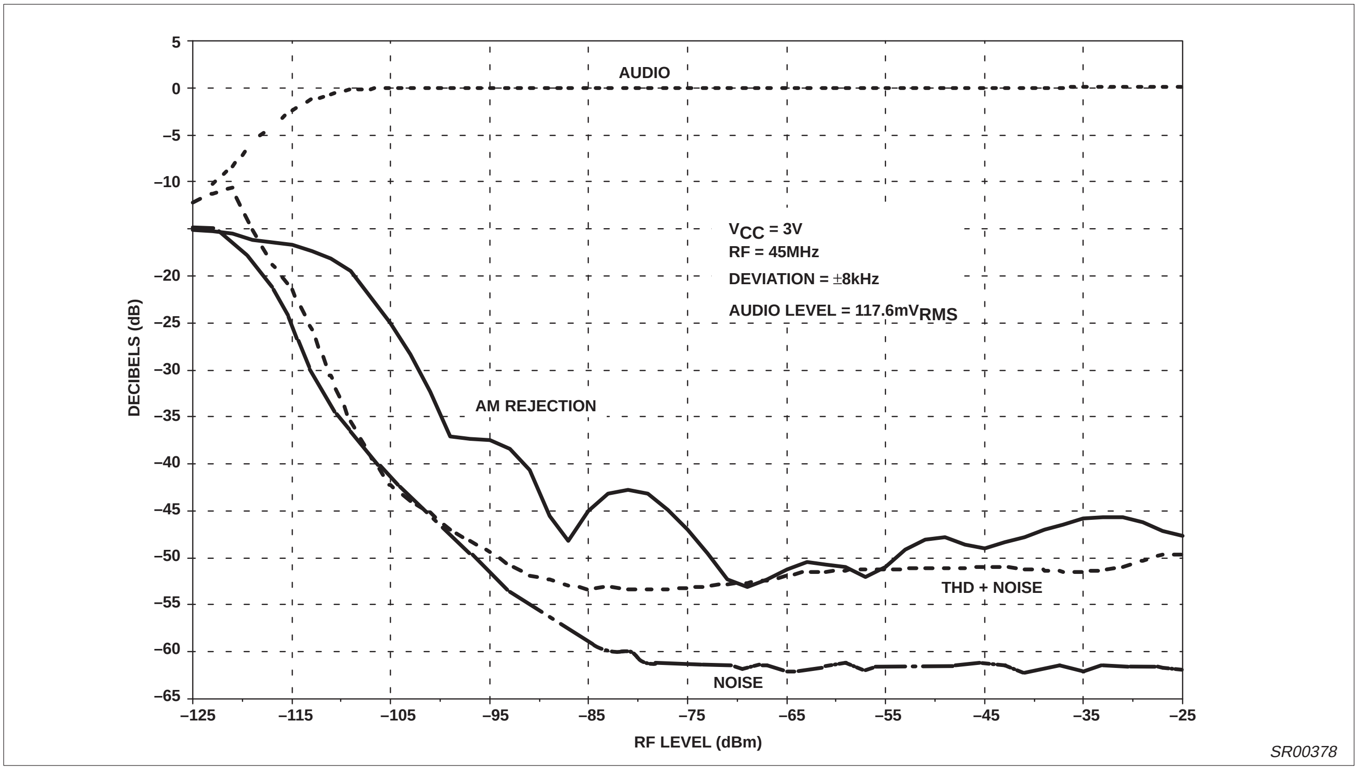


Figure 12. Sensitivity vs RF Level (+25°C)

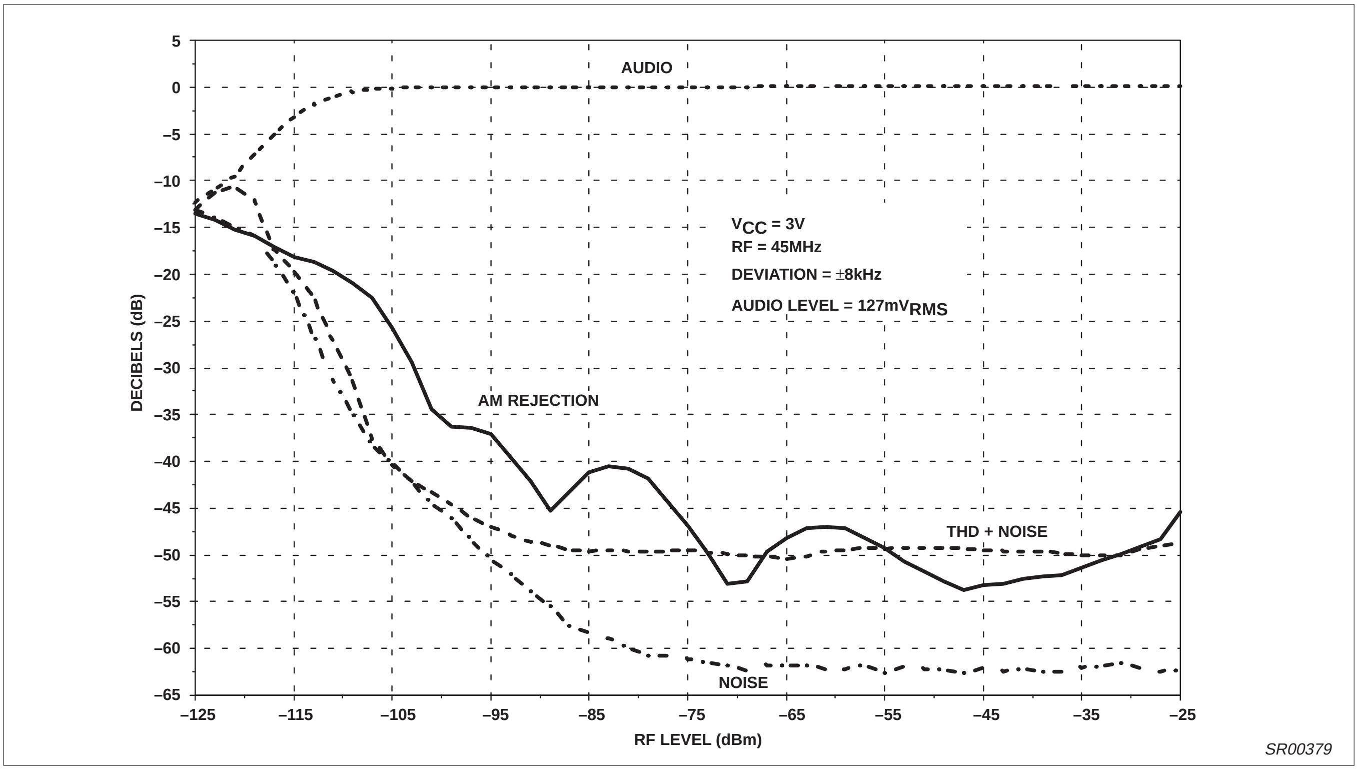


Figure 13. Sensitivity vs RF Level (Temperature 85°C)

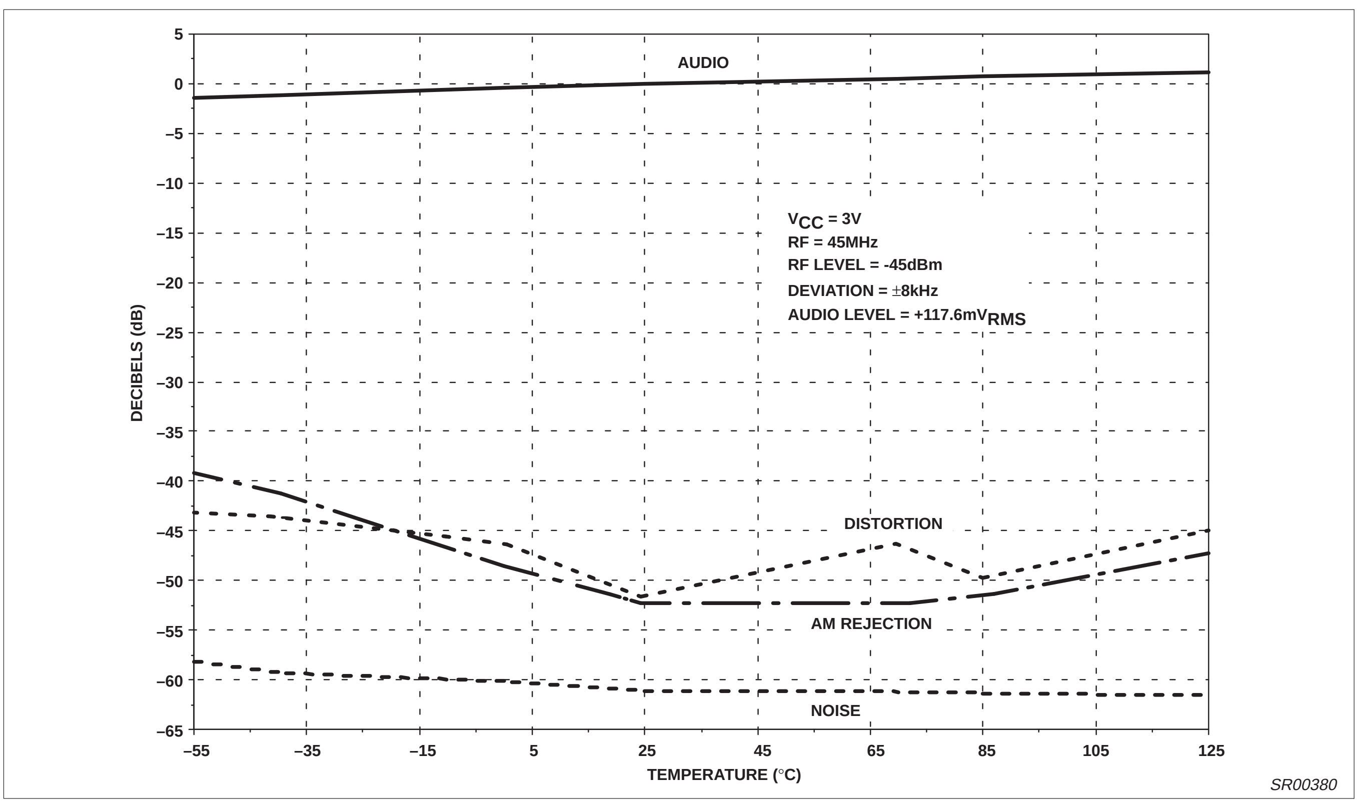


Figure 14. Relative Audio Level, Distortion, AM Rejection and Noise vs Temperature

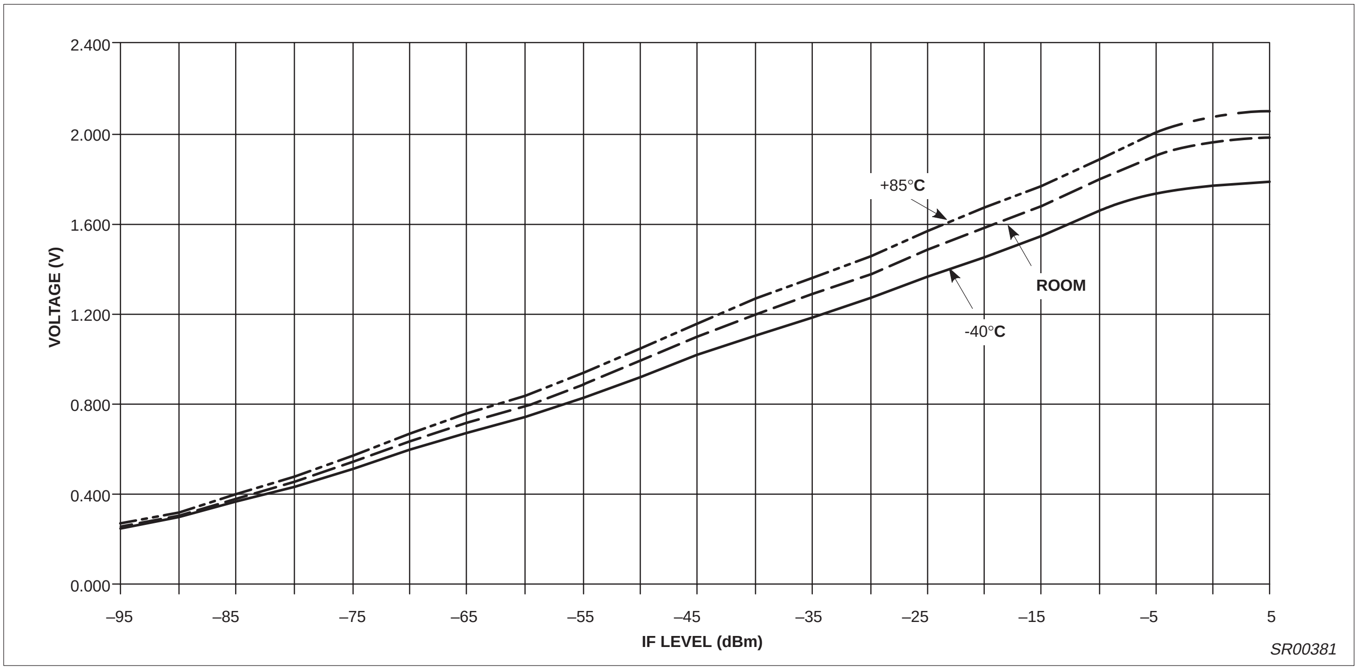


Figure 15. RSSI (455kHz IF @ 3V)

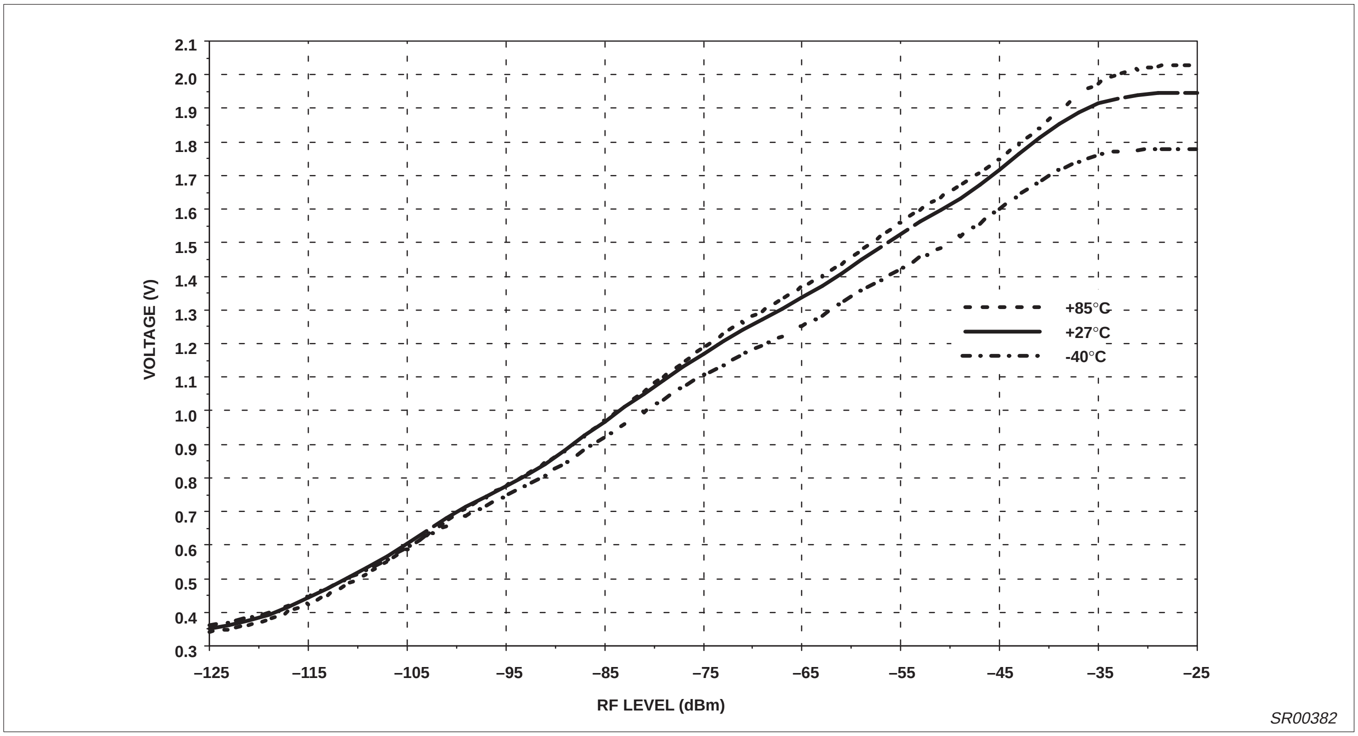


Figure 16. RSSI vs RF Level and Temperature - V_{CC} = 3V

Low-voltage high performance mixer FM IF system SA616

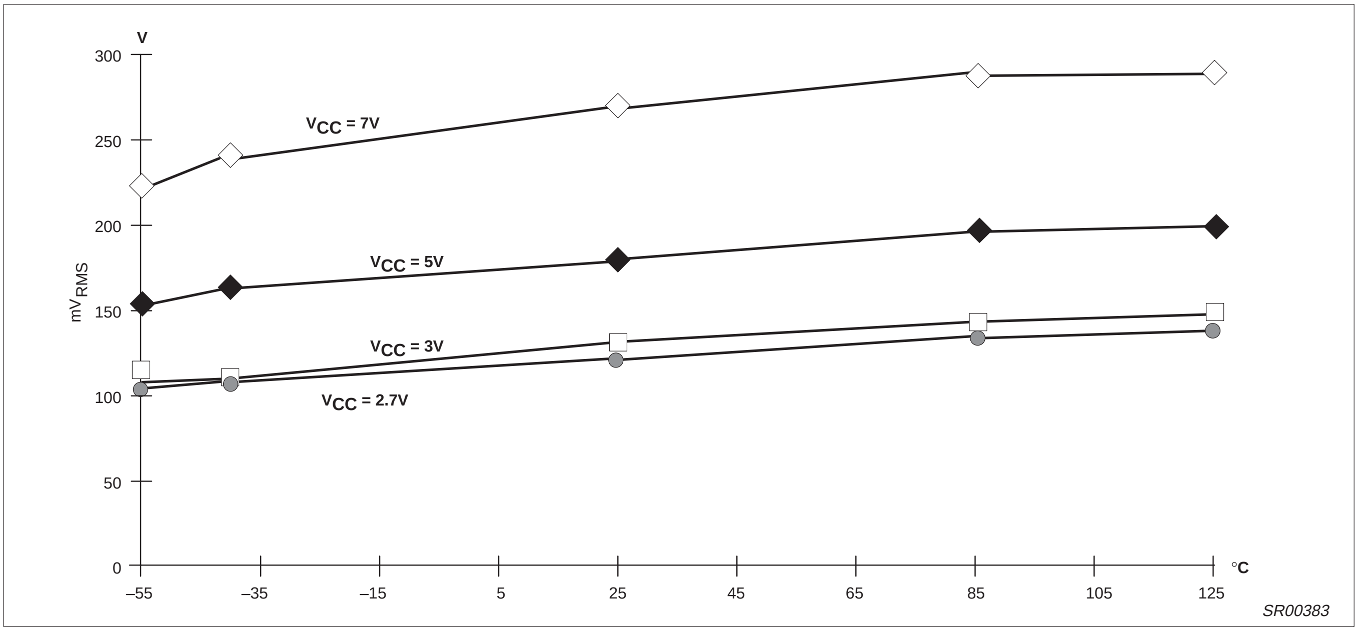
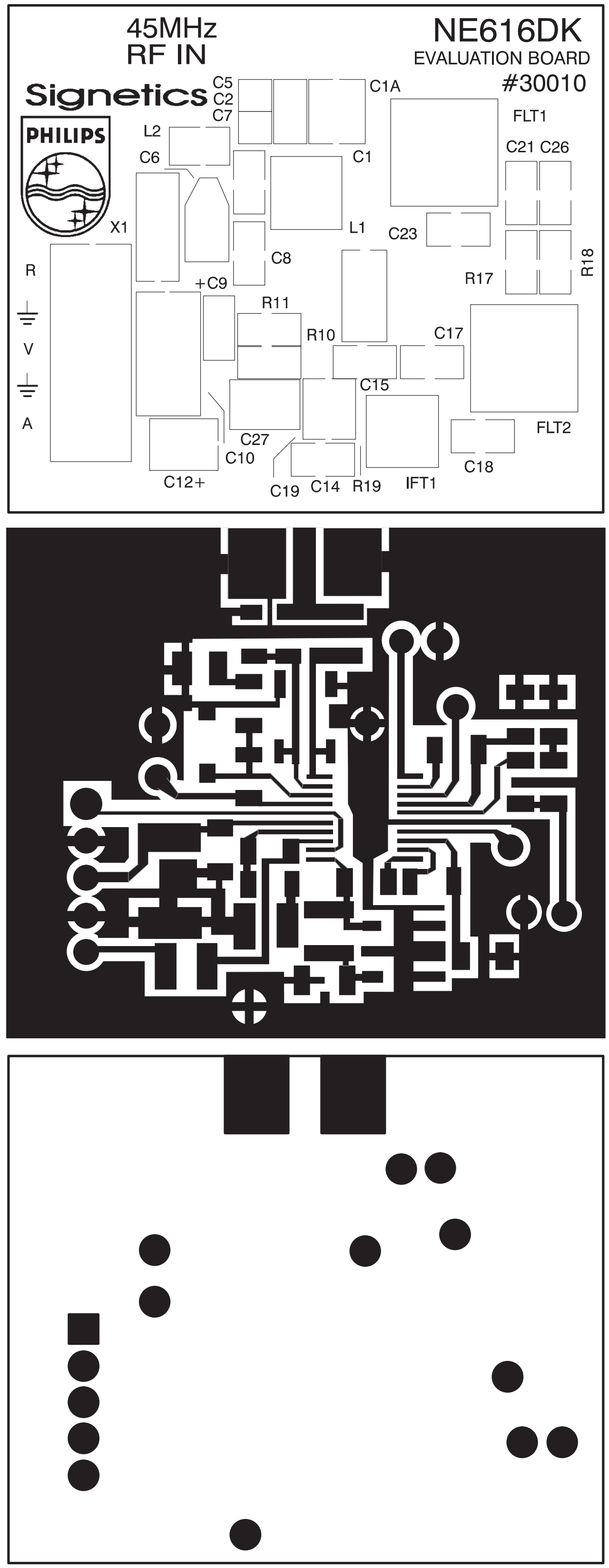


Figure 17. Audio Output vs Temperature

616 Silk Screen

616 TOP

616 BOTTOM

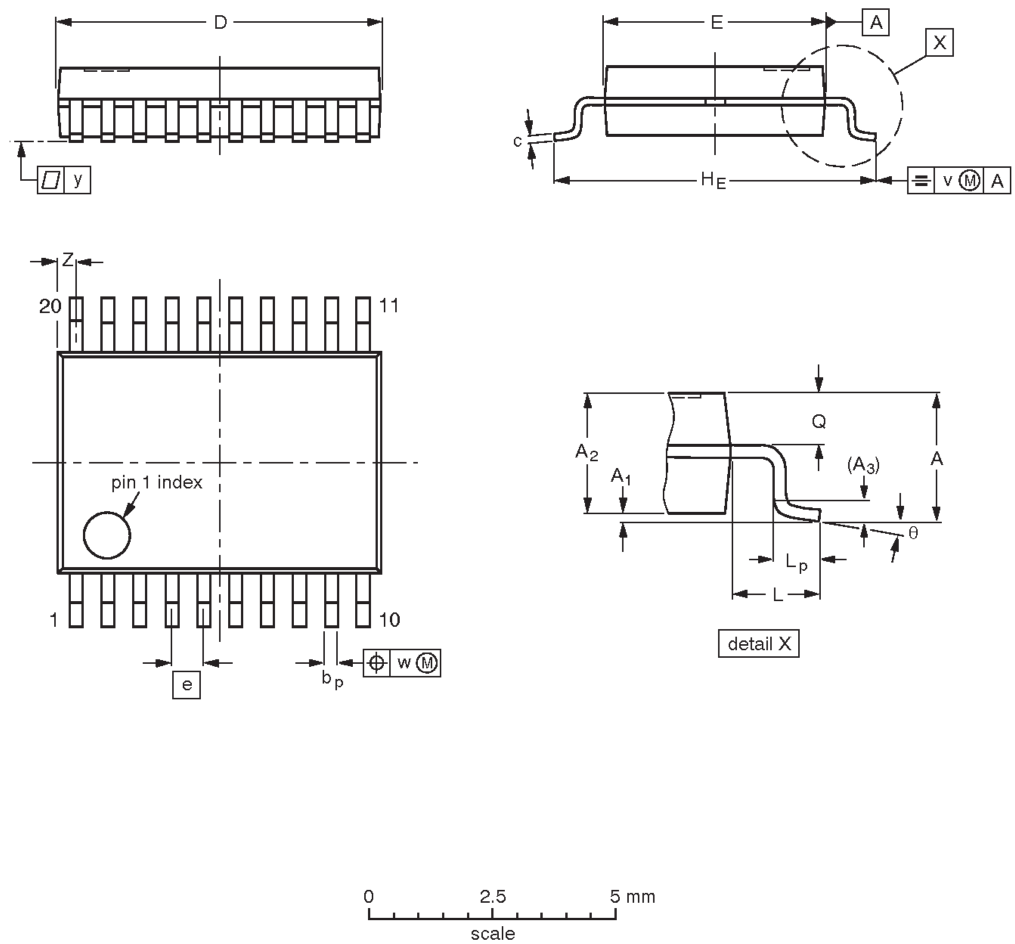


NOTE;
All views are TOP VIEW and
not actual size. For reference only.

SR00386

Figure 18.

SSOP20: plastic shrink small outline package; 20 leads; body width 4.4 mm SOT266-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D(1)	E(1)	e	H_E	L	L_p	Q	v	w	y	Z(1)	θ
mm	1.5	0.15 0	1.4 1.2	0.25	0.32 0.20	0.20 0.13	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.45	0.65 0.45	0.2	0.13	0.1	0.48 0.18	10^o 0^o

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES					EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ				
SOT266-1							~~90-04-05~~ 95-02-25

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DEFINITIONS

Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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